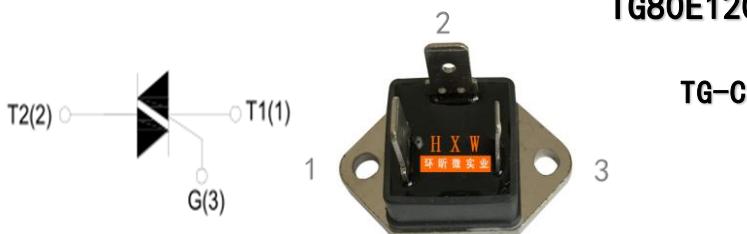


东莞市环昕微实业有限公司

TG80E120. PDF

Features

- IT(RMS): 80A
- VDRM VRMM:
600V/800V
1200V/1600V/1800V



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value
IT(RMS)	RMS on-state current	80A
VDRM	Repetitive peak off-state voltage	600V/800V/1200V/1600V/1800V
VRMM	Repetitive peak reverse voltage	600V/800V/1200V/1600V/1800V
Tj	Operating junction temperature range	~40°C ~125°C
Tstg	Storage junction temperature range	~40°C ~150°C
VDSM	Non repetitive surge peak Off-state voltage	VDRM+100V
VRSM	Non repetitive peak reverse voltage	VRMM+100V
ITSM	Non repetitive surge peak on-state current (tp=20ms)	800A
I ² t	I ² t value for fusing (tp=10ms)	3200A ² S
dI/dt	Critical rate of rise of on-state current (IG = 2 × IGT)	100A/μ s
IGM	Peak gate current	8A
PG(AV)	Average gate power dissipation	2W
PGM	Peak gate power	10W

ELECTRICAL CHARACTERISTICS (Tj =25°C unless otherwise specified)

Symbol	Test Condition	Quadrant	Value
			TG80E120
IGT	VD=12V RL=33Ω	I - II - III	<50mA
VGT		ALL	<1.3V
VGD	VD=VDRM Tj=125°C RL=3.3KΩ	ALL	>0.2V
IL		I - III	<80mA
	IG=1.2IGT	II	<120mA
IH			<70mA
dV/dt	VD=2/3VDRM Gate Open Tj=125°C		>1500V/μ s
VTM	ITM=120A tp=380μ s (Tj =25°C)		<1.5V
IDRM	VD=VDRM VR=VR RM	Tj =25°C	<20μ A
IRRM		Tj =125°C	<10mA
Rth(j-c)	junction to case (AC)	TG-C	0.31°C/W

东莞市环昕微实业有限公司

FIG.1 Maximum power dissipation versus RMS on-state current

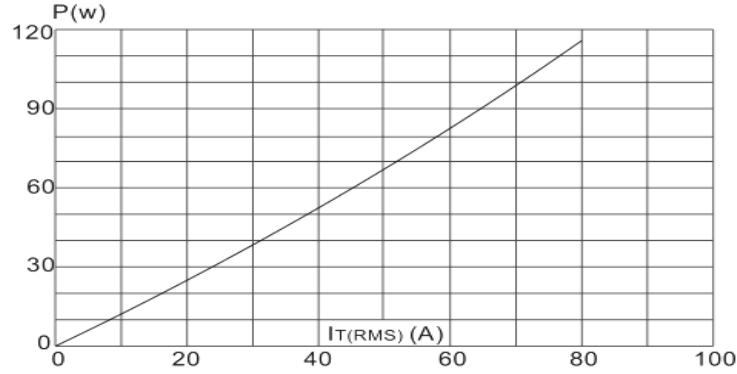


FIG.3: Surge peak on-state current versus number of cycles

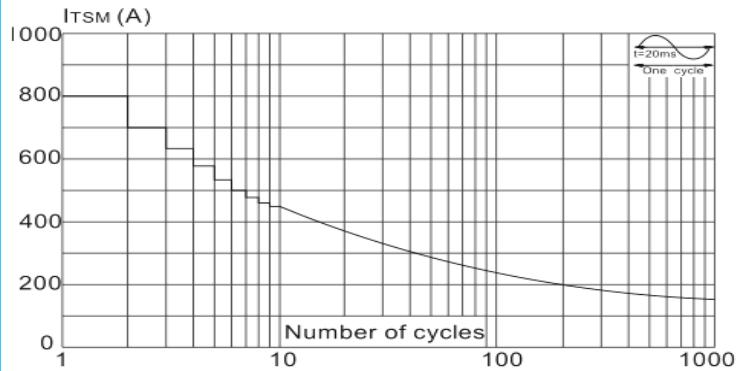


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of I^2t ($dI/dt < 100\text{A}/\mu\text{s}$)

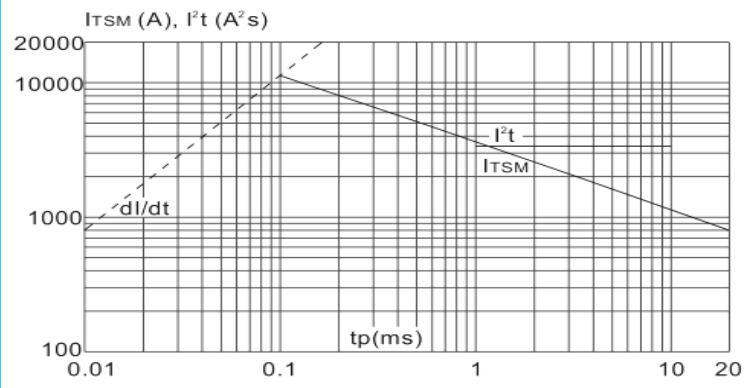


FIG.2: RMS on-state current versus case temperature

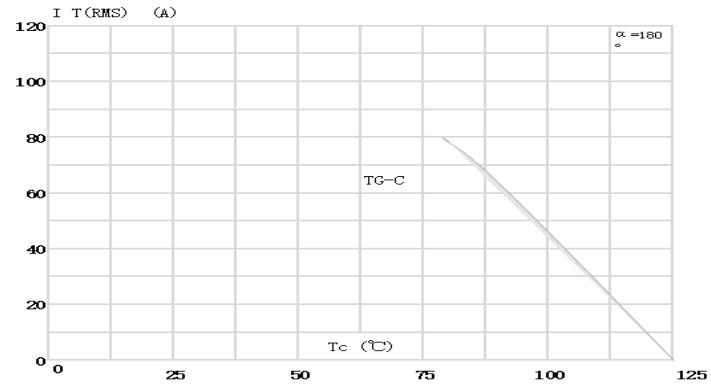


FIG.4: On-state characteristics (maximum values)

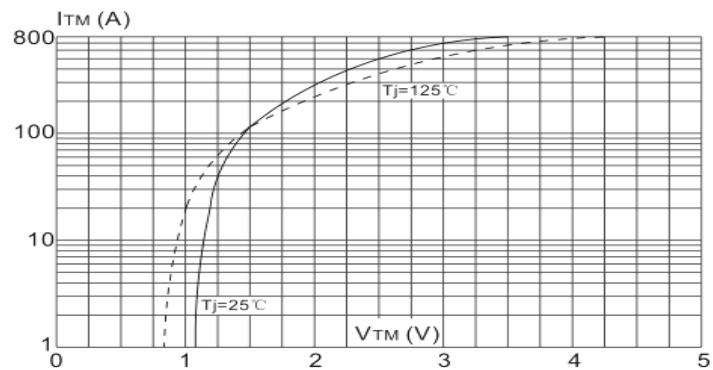
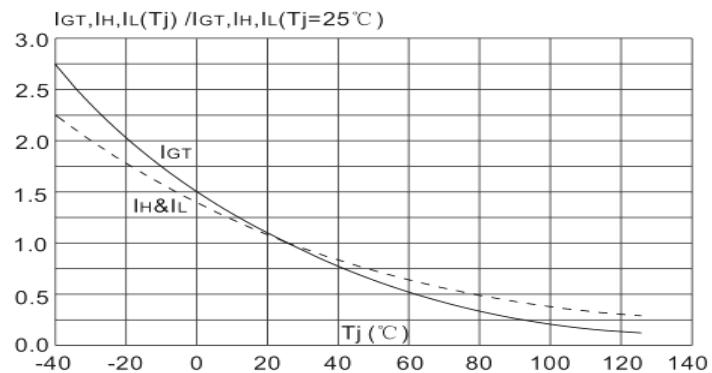


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature



PACKAGE MECHANICAL DATA

Ref.	Dimensions					
	Millimeters			Inches		
	MIn.	Typ.	Max.	MIn.	Typ.	Max.
A		39.2			1.543	
B	29.8	30.0	30.2	1.173	1.181	1.189
C		21.6			0.85	
D		20.2			0.795	
E		20.5			0.791	
F		23			0.906	
T1、T2	8.10			0.318		
T3	5.66			0.222		
T'	6.35			0.25		
t1、t2	0.8			0.031		
t3	0.6			0.023		
G	13.9			0.547		
H1	2.6			0.102		
H2	10.8			0.425		
H		22.8			0.886	
h1	6.2	6.35	6.5	0.244	0.25	0.256
h2	7.8	7.95	8.1	0.307	0.313	0.319
h3	9.45	9.75	10.05	0.372	0.384	0.396
I	2.7	3.0	3.3	0.106	0.118	0.130
J		10.8			0.425	

